NSN 5961-01-212-7306

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View Online at https://aerobasegroup.com/nsn/5961-01-212-7306 **Inclosure Material:** Metal **Overall Length:** 0.300 inches **Overall Diameter:** 0.155 inches **End Application:** Satellite communications set, an/wsc- (v) 9 **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 50.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 4.0 emitter to base voltage, static, collector open and 30.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 0.25 amperes source cutoff current **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 100.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Leads gold **Precious Material:** Gold **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: